MicroCapacitance (MC) SA SIDACtor® Device

RoHS

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These DO-214AA SAMC SIDACtor devices are intended for applications sensitive to load values. Typically, high speed connections, such as Ethernet, xDSL, and T1/E1, require a lower capacitance. Co values for the MicroCapacitance device are 40% lower than a standard SA part.

This SAMC SIDACtor series enables equipment to comply with various regulatory requirements including GR 1089, ITU K.20, K.21, and K.45, IEC 60950, UL 60950, and TIA-968-A (formerly known as FCC Part 68).

Electrical Parameters

Part Number *	V _{DRM} Volts	V _S Volts	V _T Volts	Ι _{DRM} μAmps	l _S mAmps	I _T Amps	l _H mAmps
P0080SAMCL	6	25	4	5	800	2.2	50
P0220SAMCL	15	32	4	5	800	2.2	50
P0300SAMCL	25	40	4	5	800	2.2	50

* "L" in part number indicates RoHS compliance. For non-RoHS compliant device, delete "L" from part number. For surge ratings, see table below.

General Notes:

All measurements are made at an ambient temperature of 25 °C. IPP applies to -40 °C through +85 °C temperature range.

• IPP is a repetitive surge rating and is guaranteed for the life of the product.

· Listed SIDACtor devices are bi-directional. All electrical parameters and surge ratings apply to forward and reverse polarities.

V_{DRM} is measured at I_{DRM}.

V_S is measured at 100 V/µs.

· Special voltage (V_S and V_{DRM}) and holding current (I_H) requirements are available upon request.

Surge Ratings in Amps

	Ipp										
series	0.2x310 * 0.5x700 **	2x10 * 2x10 **	8x20 * 1.2x50 **	10x160 * 10x160 **				10x1000 * 10x1000 **		I _{TSM} 50 / 60 Hz	di/dt
0,	Amps	Amps	Amps	Amps	Amps	Amps	Amps	Amps	Amps	Amps	Amps/µs
А	20	150	150	90	50	75	75	45	75	20	500

* Current waveform in μs ** Voltage waveform in μs



 $t_r = rise time to peak value$

Half Value

t - Time (µs)

 t_d = decay time to half value

Thermal Considerations

Package	Symbol	Parameter	Value	Unit
DO-214AA	TJ	Operating Junction Temperature Range	-40 to +150	°C
	TS	Storage Temperature Range	-65 to +150	°C
	R _{θJA}	Thermal Resistance: Junction to Ambient	90	°C/W

Capacitance Values

	pF		
Part Number	MIN	MAX	
P0080SAMCL	25	55	
P0220SAMCL	25	50	
P0300SAMCL	15	35	

Peak

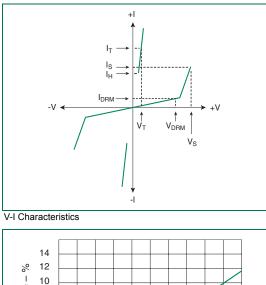
Value

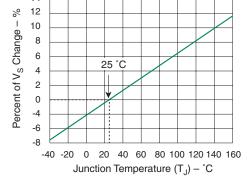
 t_{d}

Waveform = t_r x t_d

SIDACtor Devices

Note: Off-state capacitance (C_O) is measured at 1 MHz with a 2 V bias.





Normalized V_S Change versus Junction Temperature

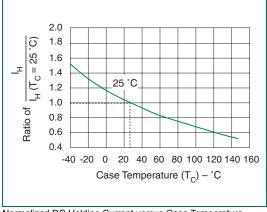


Ipp - Peak Pulse Current - %Ipp

100

50

0 [] 0 ^tr





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